## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application: Application No.: Filed:

Title:

Commissioner for Patents Washington, D.C. 20231

# POWER OF ATTORNEY BY ASSIGNEE OF ENTIRE INTEREST (REVOCATION OF PRIOR POWERS)

As assignee of record of each of the patent applications listed in the table of attachment A.

# REVOCATION OF PRIOR POWERS OF ATTORNEY

all powers of attorney previously given in each of the listed patent applications are hereby revoked, and

#### NEW POWER OF ATTORNEY

the following attorneys/agents are hereby appointed to prosecute this application and to transact all business in the Patent and Trademark Office connected therewith: I hereby appoint all attorneys of Thomas, Kayden, Horstemeyer & Risley, LLP, who are listed under the USPTO Customer Number shown below as the attorneys to prosecute this application and to transact all business in the United States Patent and Trademark Office connected therewith, recognizing that the specific attorneys listed under that Customer Number may be changed from time to time at the sole discretion of Thomas, Kayden, Horstemeyer & Risley, LLP, and request that all correspondence about the application be addressed to the address filed under the same USPTO Customer Number.

### 000047390

Patent Trademark Office

Please direct all future correspondence and telephone calls to:

Daniel R. McClure, Reg. No. 38,962 THOMAS, KAYDEN, HORSTEMEYER & RISLEY, L.L.P. 100 Galleria Parkway, Suite 1750 Atlanta, Georgia 30339

770-933-9500 ASSIGNEE OF ENTIRE INTEREST

TAIWAN SEMICONDUCTOR MANUFACTURING COMPANY, LTD.

8, Li-Hsin Rd. 6 Hsinchu Science Park Hsinchu, Taiwan 300-77, R.O.C.

#### ASSIGNEE CERTIFICATION

The certification under 37 C.F.R. §3.73(b) establishing the right of assignee to take action is attached hereto along with documentation evidencing same. Further, in my official position with Taiwan Semiconductor Manufacturing Company, Ltd., I am authorized to sign documents and otherwise act on its behalf in connection with the management and handling of patent applications and other intellectual property matters.

Date: NOJ. 25, 2004

Chien-Wei (Chris) Chou

Director - Intellectual Property Division

# Attachment A

1				T		
	No.	Serial No	TSMC No	Application Title	Filing Date	Assignment (Reel/Frame)
1	1	10/140,647	2001-0941	Prober Index Control for Remote Debugging by Web Browser	5/7/02	012902/0473
	2	10/725,810	2001-0972	Method of the Adjustable Matching Map System in Lithography	12/2/03	014761/0759
	3	10/694,426	2001-1094	Method of a Floating Pattern Loading System in Mask Dry- Etching Critical Dimension Control	10/27/03	015067/0473
٠	4	10/672,403	2001-1457	Algorithms Tunning for Dynamic Lot Dispatching in Wafer and Chip Probing	9/26/03	014554/0202
-	5	10/286,626	2001-1265	Application of Impressed-Current Cathodic Protection to Prevent Metal Corrosion and Oxidation	11/2/02	013469/0539
-	6	10/134,820	2001-1349	Method for Measuring Gate-To- Body Current of Floating-Body PD SOI MOS Devices	4/26/02	012869/0369
١			2001-1440C	Embedded DRAM for Metal- Insulator-Metal (MIM) Capacitor Structure	· 4/9/04	Recorded
	7	10/822,197				013982/0163
						at the parent application
ŀ						USP6,720,232
	8	10/749,698	2001-1510	Multivariate RBR Tool Aging Adjuster	12/31/03	014877/0720
	9	10/081,985	2001-0725	Adjustment of N and K Values in a Darc Film	2/21/02	012644/0807
	10	10/788,173	2001-1543	Chip Probing Equipment and Test Modeling for Next Generation MES(300MM)	2/26/04	015033/0283
	11	10/631,842	2002-0228	Method to Form Self-Aligned Floating Gate to Diffusion Structures in Flash	7/31/03	Filed 7/31/03
1	12	10/406,122	2001-0938	High Performance Color Filter Process for Image Sensor	4/3/03	014181/0899
١	13	10/420,594	2001-0452B	Method to Fabricate Self-Aligned Source and Drain in Split Gate Flash	4/22/03	Recorded
ĺ						012656/0769
						at the parent
						application
1						USP6,573,142
I	14	10/189,874	2001-0427	SCR-ESD Structures with Shallow Trench Isolation	7/5/02	013086/0425
	15	10/726,105	2001-0427B	SCR-ESD Structures with Shallow Trench Isolation	12/2/03	Recorded
						013086/0425
						at the parent
						application
						USP6,720.622
_						Out 0,120,022



	1				
16	10/810,965	2001-0413C	Novel Method to Improve Bump Reliability for Flip Chip Device	3/26/04	Recorded 012573/0276
					at the parent
					application
					USP6,756,294
17	10/058,474	2001-0353	(E-CRS)	1/28/02	012553/0539
18	10/725,852	2001-0088B	Effective Vcc to Vss Power ESD Protection Device	12/2/03	Recorded
					014859/0845
					at the parent
					application
					USP6,682,993
19	10/357,136	2001-0043B	Novel Low Leakage Current Cascaded Diode Structure	2/3/03	Recorded
					012326/0168
					at the parent
					application
					USP6,537,868
. 20	10/626,778	2000-0659B	Novel Test Structure for Detecting Bridging of DRAM Capacitors	7/24/03	Recorded
					011732/0773
					at the parent
					application
21	10/186,579	2000-0307B	Lossless Co-Planar Wave Guide in CMOS Process	7/1/02	USP6,617,180
					Recorded
					011498/0374
					at the parent
					application
	40,070,000		Method to Form Self-Aligned Split		USP6,465, 367
22	10/2/2,086	2002-0227	Gate Flash with L-Shaped Wordline Spacers	10/16/02	013408/0312
	18	17 10/058,474  18 10/725,852  19 10/357,136  20 10/626,778  21 10/186,579	17 10/058,474 2001-0353  18 10/725,852 2001-0088B  19 10/357,136 2001-0043B  20 10/628,778 2000-0659B  21 10/186,579 2000-0307B	10/058,474   2001-0353   Electronic Customs Release Slip (E-CRS)	Reliability for Flip Chip Device   3/25/14

Chien-Wei (Jhris) Chou Director - Intellectual Property Division